NSN 5961-01-179-7100

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Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-179-7100 **Inclosure Material:** Metal **Overall Length:** 0.122 inches **Overall Diameter:** 0.095 inches **Internal Configuration:** Junction contact-darlington connected **Mounting Method: Terminal** Features Provided: Hermetically sealed case Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter to collector, base open and 1.1 collector to emitter saturation voltage **Current Rating Per Characteristic:** 0.25 milliamperes repetitive peak forward current peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli Fiig: